Bni52 Feature

Unit size :700(W)Rotation of plate :1-150rpDiameter of plate :350mmApplied Jig :up to 4Sweep arm :up to 2Slurry feeding :auto mTimer :Max. 9Operation :Touch pNet weight:90kg (inPower Supply:100V/24Consumption current:10A/4A

700(W)x700(D)x689(H)mm (including cover) 1-150rpm 350mm up to 4 inch jig up to 2 arms (1arm standard) auto mixing and feeding Max. 99Hour 59Minutes Touch panel control 90kg (including cover) 100V/240V 10A/4A

Precision Materials Processing

BN TECHNOLOGY CORPORATION A MEMBER OF BN INTERNATIONAL GROUP

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BNi52





Extreme precise Lapping/Polishing Machine

Achieve extreme precise polishing under nano-technology environment



Bni52 System feature

Optimum system

Offer not only hardware but also optimum system as package including technology and know-how.

Capability for research laboratories up to small volume production Bni52 covers extreme precise lapping and polishing with itself and can be used for research laboratories up to small volume production.

Accuracy

Bni52 achieved extreme high accuracy that is required in nanotechnology material area.

Extreme precise CMP

Offer most optimum system under the condition that is required in planarization, uniformity of thickness.

Lappping/Polishng

BN offer best surface finish with unique and extreme precise jig / plate and background of technology, CMP etc.

Easy operation

All function, rotation of plate and abrasive auto feed etc. can be controlled with touch panel on 8.4 inch LCD panel.

Standard!!!

Resistant to chemical (Alkali and Acid) Equipped with the cover for clean room



2, 3, 4, 6 inch Jig

Polishing jig

Support samples firmly and control the pressure to the work. Jig can be customized with request. Bni52 can be applied for various application.



Addition to vacuum chuck type for wafer, holder can be customized to fit user's work.

Application

material as below.

- · GaN
- · Sapi
- · Crys
- Indiu

Failure analysis/delayering Capable for delayering, peeling off one layer by one layer extreme precisely. With delayering know-how of BN, offer polishing solution that essential to failure analysis. Extreme precise delayering with Bni52 shorten the process of failure analysis.

Optical material of crystal and sapphire.

☆

Polishing slurry Offer optimum solution that is suitable to user's application with various polishing materials, lapping powder to CMP slurry.

Polishing plate objects.





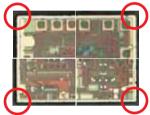
Max capability: 4 inch jig and 2 sweep arms

Leading edge semiconductor crystal material

Piled up various experiences of lapping and polishing with leading edge semiconductor crystal material, compound semiconductor

N	· SiC
phire	 Zinc oxide
stal	· GaAs
um Phosphorus	Other various Oxide Crystal

AL layer after delayering (Capable of delayering Cu layer also)



Capable for polishing various optical materials coating over surface



☆

Offer optimum polishing plate that is suitable for user's works and

Provide various plate.

- Cast iron
- Tin
- Plate for polishing cloth
- Glass
- Polyurethane

Provide optimum plate, other material, trench that is requested from users.